Diode Semiconductor Device - Page 1 of 1



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Inclo	osure Material:
Glas	S
Ove	all Length:
0.30	) inches
Tern	ninal Length:
1.00	) inches
Ove	all Diameter:
0.13	) inches
Fund	ction For Which Designed:
Volta	ige regulator
Mou	nting Method:
Term	ninal
Feat	ures Provided:
Hern	netically sealed case
Criti	cality Code Justification:
Feat	
Sem	iconductor Material:
Silico	n
Volta	age Rating In Volts Per Characteristic:
6.2	regulator voltage
Volta	age Tolerance In Percent:
-5.0/	+5.0
Curr	ent Rating Per Characteristic:
35.0	0 milliamperes source cutoff current horsepower metric
Pow	er Rating Per Characteristic:
250.	0 milliwatts small-signal input power, common-collector preset
Maxi	mum Operating Tempurature Per Measurement Point:
175.	0 degrees celsius ambient air
Spec	cial Features:
Nucl	ear hardness critical item; junction pattern arrangement: pn
Tern	ninal Type And Quantity:
2 uni	nsulated wire lead
Shel	f Life:
N/a	
Unit	Of Measure:
Dem	ilitarization:
No	
Fiig:	
A110	)a0